IMS



E3ZT-

INSTRUCTION MANUAL

! WARNING

Thank you for selecting IMS product. This sheet primarily describes precautions required in installing and operating the product. Before operating the product, read the sheet thoroughly to acquire sufficient knowledge of the product. For your convenience, keep the sheet at your disposal.

! CAUTION

Failure to follow these instructions may result in serious injury or death : Fail-safe device must be installed when using the unit with machinery that may cause serious injury or substantial economic loss. (e.g. nuclear power control, medical equipment, ships, vehicles, railways, aircraft, combustion apparatus, safety equipment, crime/disaster prevention devices,etc.) Failure to follow these instructions may result in product damage :

Do not use this unit over rated voltage ;

Do not use this unit where there is flammable or explosive gas ;

Do not use this unit where there is vibration or impact ;

In cleaning the unit, do not use water or an oil-based detergent.

Features

- High performance ASIC based advance sensor
- Long product life time, 5us modulated pulse with 1/10 duty cycle reduced aging of LED
- Build in 100ms power on delay, self-recover short circuit protection, reverse polarity, over voltage protection
- Excellent noise immunity to DC light with modulated light source and CDS signal process technology
- Mode selection for light on and dark on
- Visible super bright red light for easy alignment
- Distance adjustable
- IP65 grade

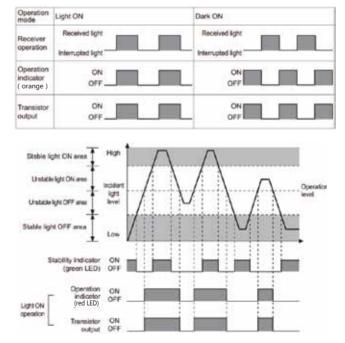
Ordering information

3ZT D		L T – C – (Light	source code)	
		Connection	type L	Cable type
			С	Connector type
		Response time		1ms
			M	0.25ms
		Sensitivity	Т	available
				Fixed
		On constitution and a	L	Light on
		Operation mode	D	Dark on
			S	Selectable
			N	NPN
			P	PNP
	0	utput	0	NPN+PNP
			D	5V
			С	Relay
			A	Analog
	Sensing o	listance unit		Unit : mm
	Sensing distar	м	Unit : m	
	(slot series u	\		
		/ Number	Sensing distance	
			Т	Through-beam
6	nsing method (D	Diffuse reflective	
Jei	Ising method (R	Retro reflective	
			V	Convergent reflective
			В	Polarization-opaquing
Item			E3Z-T	Photoelectric sensor

Sensing method		Diffuse reflective		Retro-reflective		
Model	NPN	E3ZT-D500NST	E3ZT-D1mNST	E3ZT-R2mNST	E3ZT-B500NST*(1	
	PNP	E3ZT-D500PST	E3ZT-D1mPST	E3ZT-R2mPST	E3ZT-B500PST	
Sensing distance		500mm	1m	2m	500mm	
Standard sensing object		White paper 300*300mm		Opaque: 50mm dia.	500ml transparer round bottle	
Hysteresis		Max. 20% at rated sensing distance				
Blind area		10mm				
Light source		Red LED	Infrared	Red LED	Red LED	
Power supply		10~24VDC (voltage ripple of 10%(p-p)max.)				
Current consumption		Max. 25mA				
Load current		Max. 100mA				
Operation mode		Selectable light on or dark on by key				
Indicators		Operation indicator: red, stability indicator: green				
Circuit protection		Power supply reverse polarity protection, Output short-circuit protection, and Output reverse polarity protection				
Response time		1ms				
Sensitivity adjustment		Кеу				
Ambient illumination		Incandescent lamp: Max. 3,000lx/Sunlight: Max. 10,000lx				
Ambient temperature		Operation: -25 ~ 55 °C/Storage: -25 ~ 65 °C (with no icing and condensation)				
Ambient humidity		Operation: 35 ~ 85 %/Storage: 35% ~ 95% (with no condensation)				
Insulation resistance		Min. 20MΩ (500VDC)				
Dielectric strength		1,000 VAC at 50/60 Hz for 1 min. between current-carrying parts and case				
Vibration resistance		1.5mm amplitude at frequency of 10 to 55Hz in each of X,Y,Z direction for 2 hours				
Shock resistance		500m/s ² in X,Y,Z directions for 3 times				
Protection Degree		IEC: IP65				
Connection method		Cable				
Line color definition		Brown: 10~24VDC, Blue: GND, Black: output				
Weight		Approx. 50g				
Material	Case	PBT				

*(1) E3ZT-B is for transparent objects detection.

Operating timing diagram



% The waveforms of "Operation indicator" and "Transistor output" are for Light on mode.

Specifications

